



Docket No.: M4065:0051/P051-A
(PATENT)

2/27/04
7-10-03
[Signature]

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Leonard Forbes, et al.

Application No.: 09/609,813

Group Art Unit: 2815

Filed: July 3, 2000

Examiner: P. II

Under
8/13/03

For: HIGH DENSITY PLANAR SRAM CELL
USING BIPOLAR LATCHUP AND GATED
DIODE BREAKDOWN

AMENDMENT AFTER FINAL ACTION (37 C.F.R. SECTION 1.116)

MS AF
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

RECEIVED
JUN - 7 2003
TECHNOLOGY CENTER 2800

INTRODUCTORY COMMENTS

In response to the Office Action dated April 2, 2003 (Paper No. 26), finally rejecting claims 48-65, please amend the above-identified U.S. patent application as follows:

SUMMARY OF AMENDMENTS

SPECIFICATION

☒ There are no amendments to the specification.
☐ Marked up replacement(s) paragraphs are presented in a separate section.

CLAIMS

There are no amendments to the claims.

Application No.: 09/609,813

Docket No.: M4065.0051/P051-A

X A complete listing of all claims ever present in this case in ascending order with status identifier is presented in a separate section.